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TOIREX

XP162A11C0PR-G

ETR1125_003

Power MOSFET

■GENERAL DESCRIPTION

The XP162A11C0PR-G is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics. Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

A gate protect diode is built-in to prevent static damage.

The small SOT-89 package makes high density mounting possible.

■APPLICATIONS

- ●Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance : Rds(on) = 0.15Ω @ Vgs = -10 V

: Rds(on) = 0.28Ω @ Vgs = -4.5V

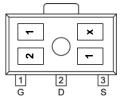
Ultra High-Speed Switching
Driving Voltage : -4.5V
Gate Protect Diode Built-in
P-Channel Power MOSFET

DMOS Structure

Small Package : SOT-89

Environmentally Friendly: EU RoHS Compliant, Pb Free

■ PIN CONFIGURATION/ MARKING



G : Gate S : Source

o . Source

D : Drain

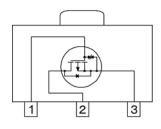
SOT-89

■ PRODUCT NAME

PRODUCTS	PACKAGE	ORDER UNIT
XP162A11C0PR	SOT-89	1,000/Reel
XP162A11C0PR-G ^(*)	SOT-89	1,000/Reel

^(*) The "-G" suffix denotes Halogen and Antimony free as well as being fully RoHS compliant.

■EQUIVALENT CIRCUIT



P-channel MOSFET (1 device built-in)

■ ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	-30	V
Gate-Source Voltage	Vgss	±20	V
Drain Current (DC)	ld	-2.5	Α
Drain Current (Pulse)	Idp	-10	Α
Reverse Drain Current	ldr	-2.5	Α
Channel Power Dissipation *	Pd	2	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55~150	°C

^{*} When implemented on a ceramic PCB

^{*} x represents production lot number.

■ELECTRICAL CHARACTERISTICS

DC Characteristics $Ta = 25^{\circ}C$

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds= -30V, Vgs= 0V	-	-	-10	μΑ
Gate-Source Leak Current	Igss	Vgs= ±20V, Vds= 0V	-	-	±10	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	Id= -1mA, Vds= -10V	-1.0	-	-2.5	V
Drain-Source On-State Resistance*1	Rds(on)	Id= -1.5A, Vgs= -10V	-	0.11	0.15	Ω
		Id= -1.5A, Vgs= -4.5V	-	0.20	0.28	Ω
Forward Transfer Admittance*1	Yfs	Id= -1.5A, Vds= -10V	-	2.5	-	S
Body Drain Diode Forward Voltage	Vf	If= -2.5A, Vgs= 0V	-	-0.85	-1.1	V

^{*1} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds= -10V, Vgs=0V f= 1MHz	-	280	-	pF
Output Capacitance	Coss		-	200	-	pF
Feedback Capacitance	Crss		-	90	-	pF

Switching Characteristics

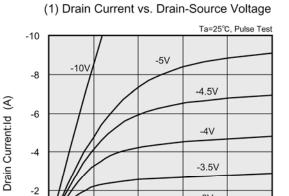
Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs= -5V, Id= -1.5A Vdd= -10V		10	-	ns
Rise Time	tr		-	30	-	ns
Turn-Off Delay Time	td (off)		-	20	-	ns
Fall Time	tf		-	35	-	ns

Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a ceramic PCB	-	62.5	-	°C/W

■TYPICAL PERFORMANCE CHARACTERISTICS





-3

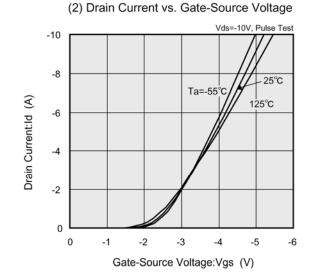
-2

0

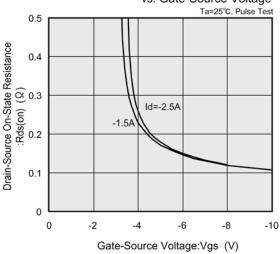
-3V Vgs=-2.5V

-4

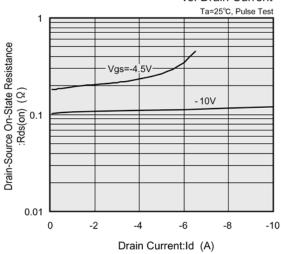
-5



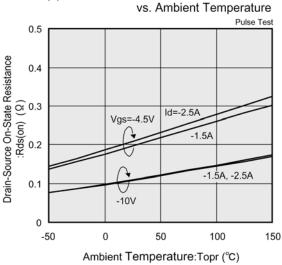




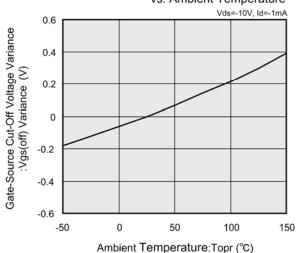
(4) Drain-Source On-State Resistance vs. Drain Current



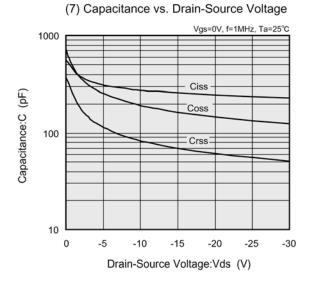
(5) Drain-Source On-State Resistance

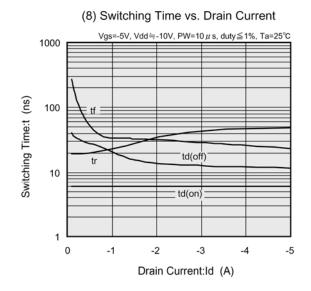


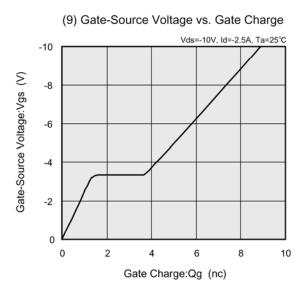
(6) Gate-Source Cut-Off Voltage Variance vs. Ambient Temperature

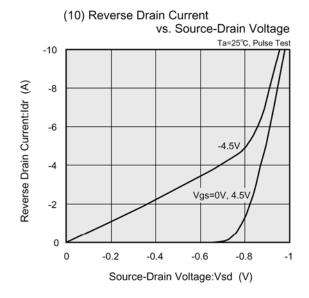


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

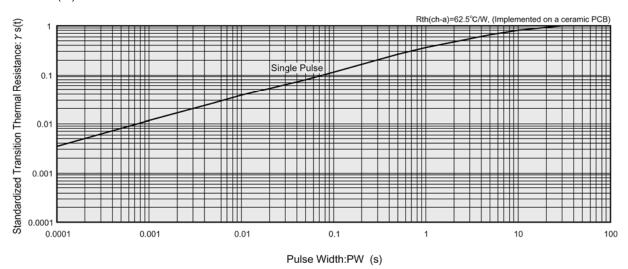








(11) Standardized transition Thermal Resistance vs. Pulse Width



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